

Nch 600V 3A Power MOSFET

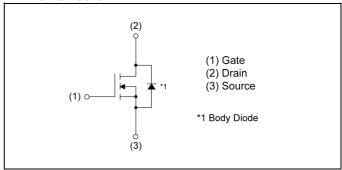
V _{DSS}	600V
R _{DS(on)} (Max.)	1.5Ω
I _D	±3A
P _D	44W

Outline TO-252

Features

- 1) Low on-resistance
- 2) Ulta fast switching speed
- 3) Parallel use is easy
- 4) Pb-free plating; RoHS compliant

•Inner circuit



Application

Switching Power Supply

Packaging specifications

Packing	Embossed Tape
Packing code	TL1
Marking	R6003K
Basic ordering unit (pcs)	2500

ullet Absolute maximum ratings (T_a = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage	V _{DSS}	600	V	
Continuous drain current (T _c = 25°C)	I _D *1	±3	А	
Pulsed drain current	I _{DP} *2	±9	А	
Coto Columbia valtana	static	.,	±20	V
Gate - Source voltage	AC(f>1Hz)	$ V_{GSS}$	±30	V
Avalanche current, single pulse		I _{AS}	0.5	А
Avalanche energy, single pulse		E _{AS} *3	13.4	mJ
Power dissipation $(T_c = 25^{\circ}C)$	P _D	44	W	
Junction temperature	T _j	150	°C	
Operating junction and storage temper	rature range	T _{stg}	-55 to +150	°C

●Thermal resistance

Downwortow	Cymah al	Values			1.124
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC} *4	-	-	2.9	°C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	-	265	°C

● Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit	
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	600	1	-	V	
		$V_{DS} = 600V, V_{GS} = 0V$					
Zero gate voltage drain current	I _{DSS}	$T_j = 25^{\circ}C$	-	-	100	μΑ	
		$T_j = 125^{\circ}C$	-	-	1000		
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±100	nA	
Gate threshold voltage	$V_{GS(th)}$	V _{DS} = 10V, I _D = 1mA	3.5	-	5.5	V	
		V _{GS} = 10V, I _D = 1A					
Static drain - source on - state resistance	R _{DS(on)} *5	$T_j = 25^{\circ}C$	-	1.3	1.5	Ω	
		$T_j = 125^{\circ}C$	-	2.5	-		
Gate resistance	R_{G}	f = 1MHz, open drain	-	4	-	Ω	

● Electrical characteristics (T_a = 25°C)

Darramatar	Symbol Conditions		Values			Linit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Forward Transfer Admittance	$ Y_{fs} ^{*5}$ $V_{DS} = 10V, I_D = 1.5A$		0.8	1.6	-	S	
Input capacitance C_{iss} $V_{GS} = 0V$		V _{GS} = 0V	-	185	-		
Output capacitance	C _{oss}	V _{DS} = 25V	-	205	-	pF	
Reverse transfer capacitance	Reverse transfer capacitance C_{rss} $f = 1$		-	12	-		
Turn - on delay time	m - on delay time $t_{d(on)}^{*5}$ $V_{DD} \simeq 300 \text{V}, V_{GS}$		-	17	-		
Rise time	t _r *5	I _D = 1.5A	-	17	-	no	
Turn - off delay time $t_{d(off)}^{5}$ $R_{L} \simeq$		$R_L \simeq 200\Omega$	-	32	-	ns	
Fall time	t _f *5	$R_G = 10\Omega$	-	40	-		

● Gate charge characteristics (T_a = 25°C)

Davamatar	Symbol Conditions -		Values			l limit
Parameter			Min.	Тур.	Max.	Unit
Total gate charge	Q_g^{*5}	V _{DD} ≈ 300V	-	8	-	
Gate - Source charge	Q _{gs} *5	I _D = 3A	-	2.3	-	nC
Gate - Drain charge	Q _{gd} *5	V _{GS} = 10V	-	3.5	-	
Gate plateau voltage	V _(plateau)	V _{DD} ≈ 300V, I _D = 3A	-	6.8	-	V

^{*1} Limited only by maximum junction temperature allowed.

^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} L $\stackrel{=}{=}$ 100mH, V_{DD}=50V, R_G=25 Ω , STARTING T_j=25 $^{\circ}$ C

^{*4} T_C=25°C

^{*5} Pulsed

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Cumbal	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	UTIIL	
Source current	I _S *1	T - 25°C	1	-	3	Α	
Pulsed source current	I _{SP} *2	$T_C = 25^{\circ}C$		-	9	Α	
Source-Drain voltage	V _{SD} *5	$V_{GS} = 0V$, $I_S = 3A$	-	-	1.5	V	
Reverse recovery time	t _{rr} *5		-	240	-	ns	
Reverse recovery charge	Q _{rr} *5	$I_S = 3A$ di/dt = 100A/µs	-	0.86	-	μC	
Peak reverse recovery current	_{rr} *5		-	7.0	-	А	

Fig.1 Power Dissipation Derating Curve

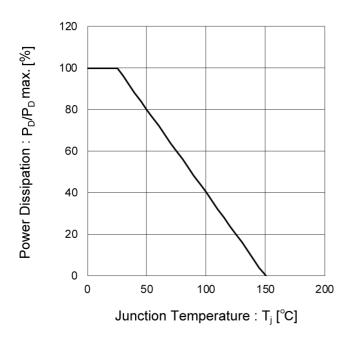


Fig.2 Drain Current Derating Curve

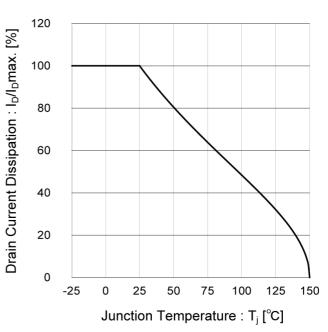


Fig.3 Transient Thermal Resistance vs. Pulse Width

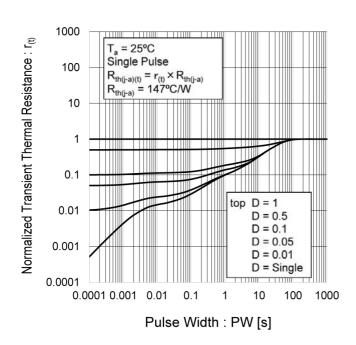


Fig.4 Maximum Safe Operating Area

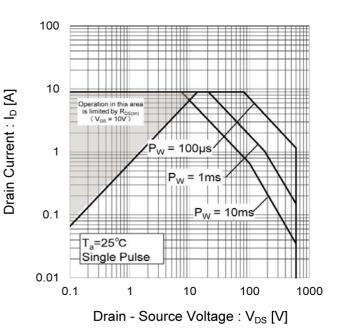


Fig.5 Avalanche Energy DeratingCurve vs. Junction Temperature

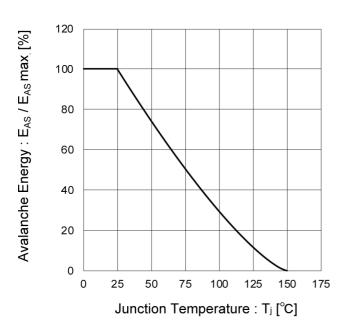


Fig.6 Breakdown Voltage vs. Junction Temperature

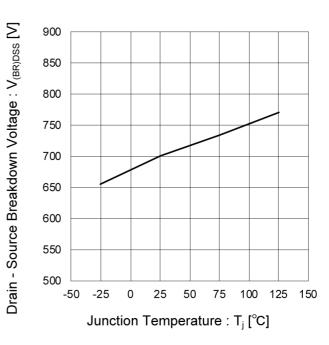
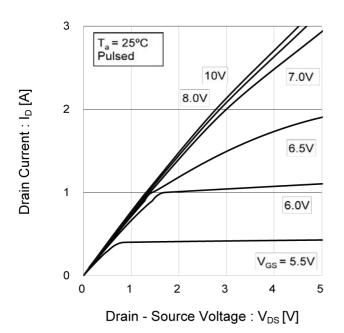


Fig.7 Typical Output Characteristics(I)



Drain Current : I_D [A]

3 T_a = 25°C Pulsed 10V 8.0V 7.0V 2 6.5V 6.0V 1 $V_{GS} = 5.5V$ 0 0 10 20 30 50 Drain - Source Voltage: V_{DS} [V]

Fig.8 Typical Output Characteristics(II)

Fig.9 Gate Threshold Voltage vs. Drain Current

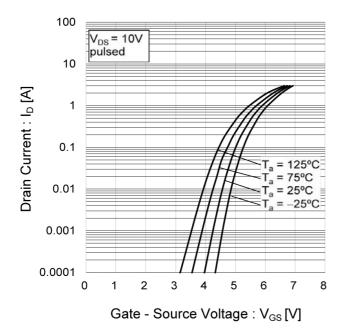


Fig.10 Gate Threshold Voltage vs. Junction Temperature

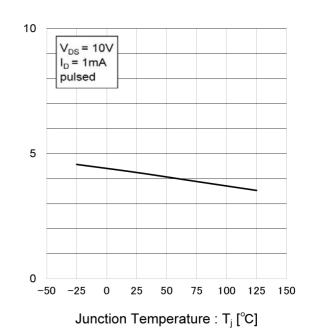
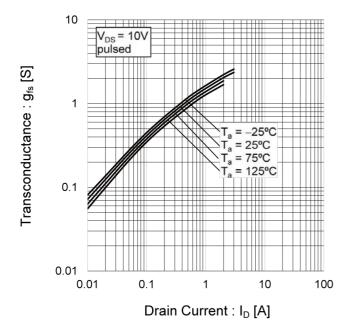


Fig.11 Forward Transfer Admittance vs. Drain Current



Gate Threshold Voltage : $V_{GS(th)}[V]$

Fig.12 Static Drain - Source On - State Resistance vs. Drain Current

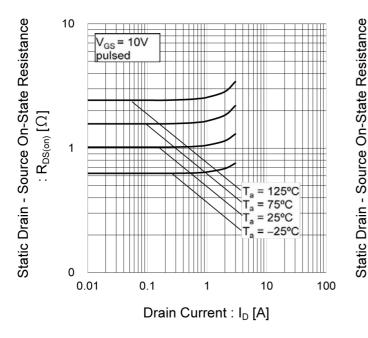


Fig.13 Static Drain - Source On - State
Resistance vs. Gate Source Voltage

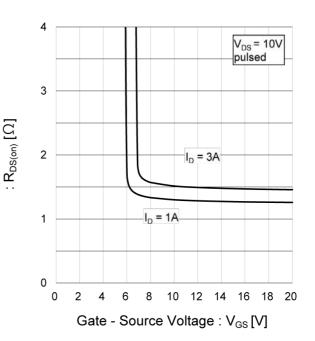


Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature

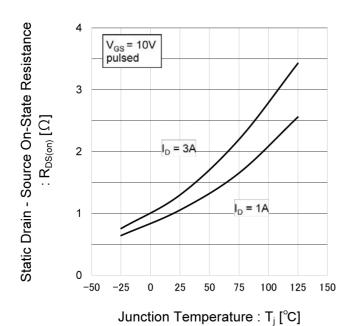


Fig.15 Typical Capacitance vs. Drain - Source Voltage

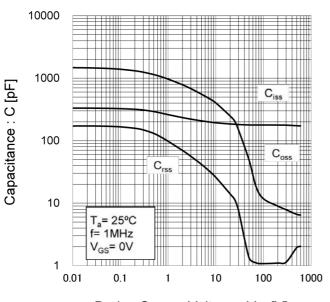
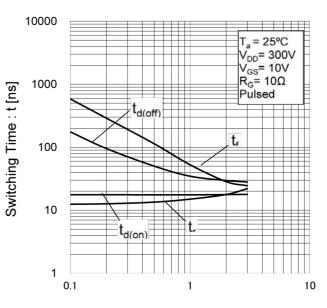


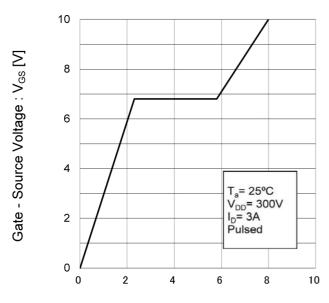
Fig.16 Switching Characteristics



Drain - Source Voltage : V_{DS} [V]

Drain Current : I_D [A]

Fig.17 Typical Gate Charge



Total Gate Charge : Q_g [nC]

Fig.18 Souce Current vs. Source-Drain Voltage

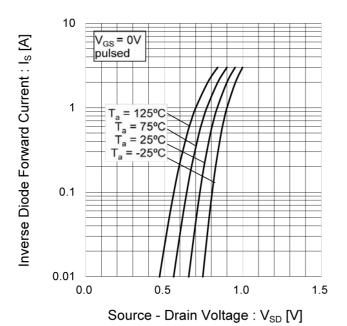
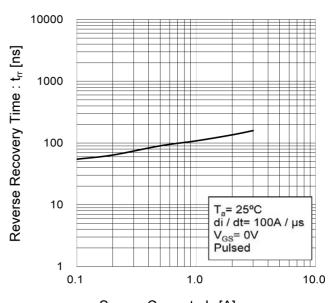


Fig.19 Reverse Recovery Time vs. Source Current



Source Current : I_S [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

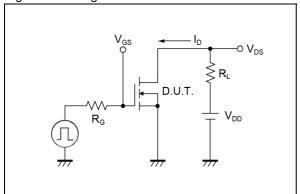


Fig.2-1 Gate Charge Measurement Circuit

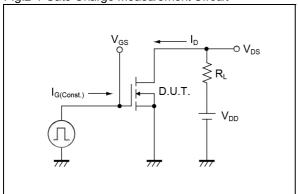


Fig.3-1 Avalanche Measurement Circuit

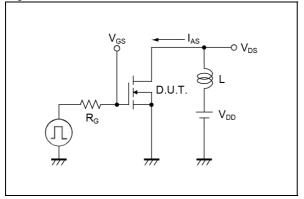


Fig.4-1 Reverse Recovery Time

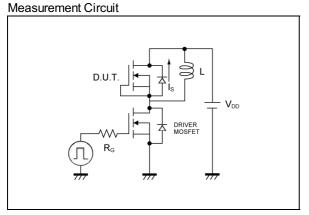


Fig.1-2 Switching Waveforms

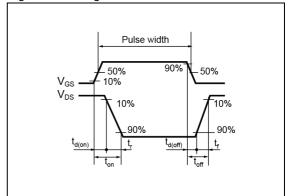


Fig.2-2 Gate Charge Waveform

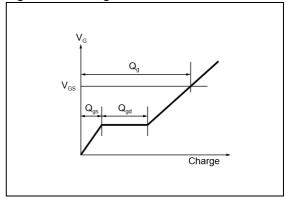


Fig.3-2 Avalanche Waveform

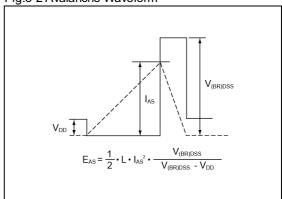
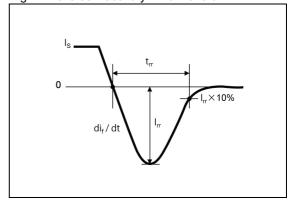
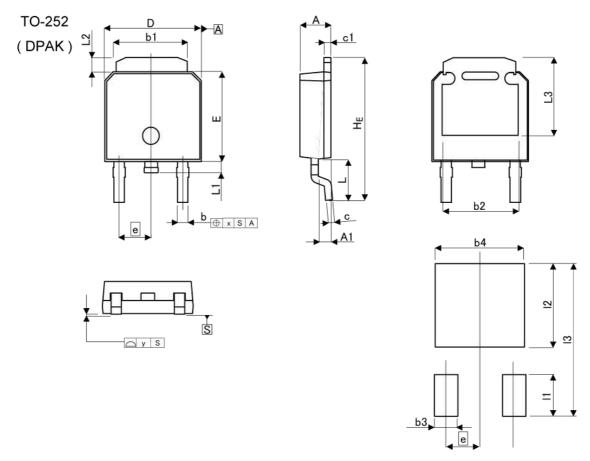


Fig.4-2Reverse Recovery Time Waveform





Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM -	MILIME	ETERS	INCI	HES
	MIN	MAX	MIN	MAX
Α	2.20	2.40	0.087	0.094
A1	0.70	1.10	0.028	0.043
b	0.60	0.90	0.024	0.035
b1	5.20	5.50	0.205	0.217
b2	5.	35	0.2	211
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.40	6.80	0.252	0.268
е	2.	30	0.091	
E	6.00	6.40	0.236	0.252
HE	9.40	10.40	0.370	0.409
L	2.	70	0.1	06
L1	0.60	1.00	0.024	0.039
L2	0.70	1.30	0.028	0.051
L3	5.	30	0.2	209
х	74 ·	0.25	а	0.010
у	(71)	0.10	-	0.004

DIM	MILIM	ETERS	INCHES	
DIIVI	MIN	MAX	MIN	MAX
b3	727	1.15	2	0.045
b4	-	5.55	ж	0.219
11	(2/)	2.77	2	0.109
12	-	5.50	-	0.217
13	2	10.40	2	0.409

Dimension in mm/inches



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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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